Application No.: 10/810,659 Docket No.: 8733.341.10 US

Amendment Response dated January 17, 2008
Response to Office Action dated October 18, 2007

LISTING OF THE CLAIMS

1-18. (Canceled)

19. (Currently Amended) An array substrate for an active matrix type liquid crystal display

(LCD) device, comprising:

a substrate;

a gate line on said substrate, wherein said gate line includes a gate pad;

a first insulating layer on said gate line and said substrate;

a semiconductor layer on said first insulating layer and over a portion of said gate line;

a data line over said first insulating layer and that crosses said gate line, said data line

including a protruding portion that projects in a direction of said semiconductor layer and that

forms a source electrode, wherein an end portion of the semiconductor layer under the data line

is substantially a same width as an end portion of the data line, wherein said data line further

includes a data pad;

a drain electrode spaced apart from said source electrode and extending into a rectangular

region partially defined by said gate and data lines;

a passivation layer on said drain electrode, said passivation layer having a drain contact

hole that exposes said drain electrode; and

a pixel electrode formed over the passivation layer, said pixel electrode electrically

connecting to said drain electrode via said drain contact hole, wherein said pixel electrode

extends over a portion of said gate line so as to form a storage capacitor comprised of a capacitor

electrode extending from the pixel electrode, said gate line, and said first insulating layer

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therebetween, wherein said storage capacitor further includes a short-preventing part disposed

between said pixel electrode and said gate line,

wherein the short-preventing part has a stepped portion that overlaps a stepped end

portion of the gate line, and wherein said short-preventing part includes said semiconductor layer

and said passivation layer.

20. (Canceled)

21. (Currently Amended) The array substrate of claim 20-19, wherein said short-preventing part

further includes an ohmic contact layer, and a conducting material between said semiconductor

layer and said passivation layer.

22. (New) An array substrate for an active matrix type liquid crystal display (LCD) device,

comprising:

a substrate;

a gate line on said substrate, wherein said gate line includes a gate pad;

a first insulating layer on said gate line and said substrate;

a semiconductor layer on said first insulating layer and over a portion of said gate line;

a data line over said first insulating layer and that crosses said gate line, said data line

including a protruding portion that projects in a direction of said semiconductor layer and that

forms a source electrode, wherein an end portion of the semiconductor layer under the data line

is substantially a same width as an end portion of the data line, wherein said data line further

includes a data pad;

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a drain electrode spaced apart from said source electrode and extending into a rectangular

region partially defined by said gate and data lines;

a passivation layer on said drain electrode, said passivation layer having a drain contact

hole that exposes said drain electrode; and

a pixel electrode formed over the passivation layer, said pixel electrode electrically

connecting to said drain electrode via said drain contact hole, wherein said pixel electrode

extends over a portion of said gate line so as to form a storage capacitor comprised of a capacitor

electrode extending from the pixel electrode, said gate line, and said first insulating layer

therebetween, wherein said storage capacitor further includes a short-preventing part disposed

between said pixel electrode and said gate line, and wherein said short-preventing part includes

said semiconductor layer and said passivation layer.

23. (New) The array substrate of claim 22, wherein the short-preventing part is scattered

around the overlapped portion of the gate line.

24. (New) The array substrate of claim 22, wherein the short-preventing part covers a

whole width of the gate line.

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